

1. Description

These diodes are optimized to less losses and EMI/RFI in high frequency power conditioning system. The soft recovery character of the diodes offers buffer in most applications. These devices are suited for power converters and other applications where the switching losses are not significant portion of the total losses.

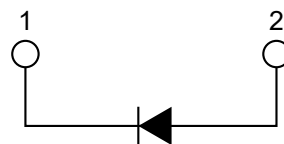
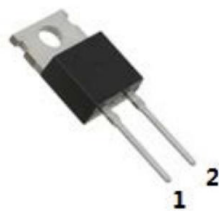
2. Features

- Ultrafast Recovery
- 175°C operating junction temperature
- High frequency operation
- Low IR value
- Very Low forward voltage
- Epitaxial chip construction

3. Applications

- Switched mode power supply
- UPS
- Free wheeling diode, Snubber diode

4. Pinning Information



TO-220AC-2



5. Absolute Maximum Ratings

Parameter	Symbol	Test Conditions	Value	Units
Repetitive peak reverse voltage	V_{RRM}		1200	V
Blocking voltage	V_R		1200	V
Continuous forward current	$I_{F(AV)}$	$T_A=110^{\circ}\text{C}$	30	A
Single pulse forward current ¹	I_{FSM}	$T_A=25^{\circ}\text{C}$	170	A
Maximum repetitive forward current	I_{FRM}	Square wave, 20kHz	45	A
Operating junction	T_J		175	$^{\circ}\text{C}$
Storage temperatures	T_{STG}		-55 to 175	$^{\circ}\text{C}$

Note: 1. $t=10\text{ms}$, (50Hz), sine, $V_R=0\text{V}$

6. Electrical Characteristics ($T_A = 25^{\circ}\text{C}$ Unless otherwise specified)

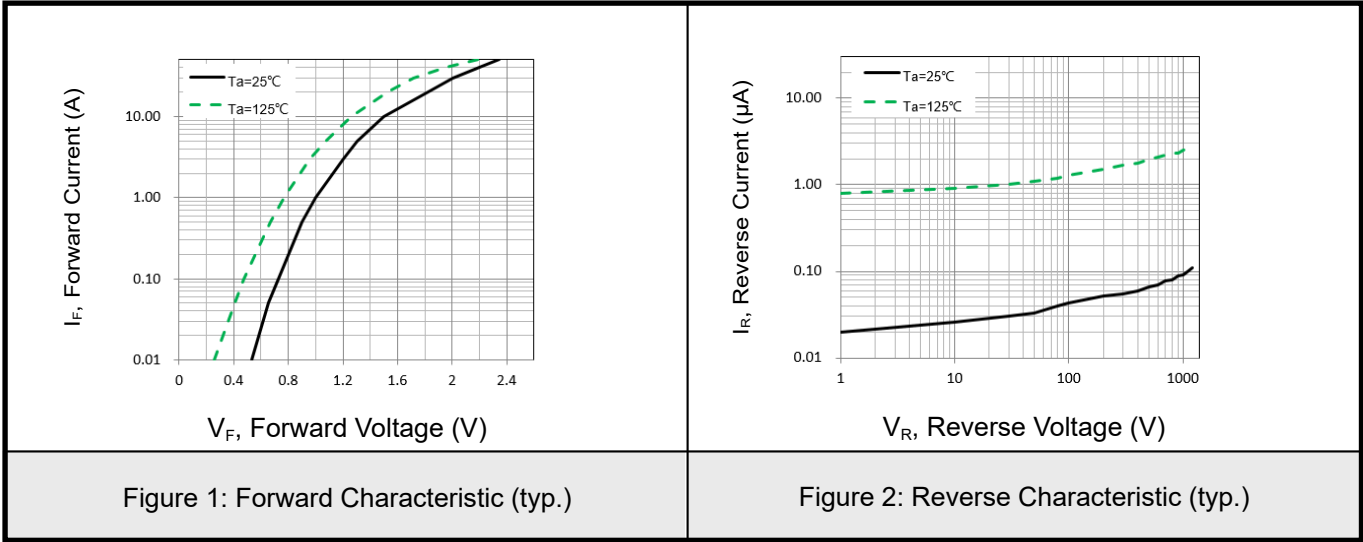
Parameter	Symbol	Conditions	Min	Typ	Max	Units
Breakdown voltage	V_{BR}	$I_R=100\mu\text{A}$	1200			V
Forward voltage	V_F	$I_F=30\text{A}$		2	2.6	V
		$I_F=30\text{A}$, $T_J=125^{\circ}\text{C}$		1.7	2.3	V
Reverse leakage current	I_R	$V_R=V_{RRM}$			30	μA
		$T_J=150^{\circ}\text{C}$, $V_R=1200\text{V}$			300	μA
Reverse recovery time	t_{rr}	$I_F=0.5\text{A}$, $I_R=1\text{A}$, $I_{RR}=0.25\text{A}$			65	ns
		$I_F=1\text{A}$, $V_R=30\text{V}$, $di/dt=200\text{A}/\mu\text{s}$		35	45	ns

7. Thermal Characteristics

Parameter	Symbol	Typ	Max	Units
Junction-to-Case	R_{thJC}		2.5	$^{\circ}\text{C}/\text{W}$

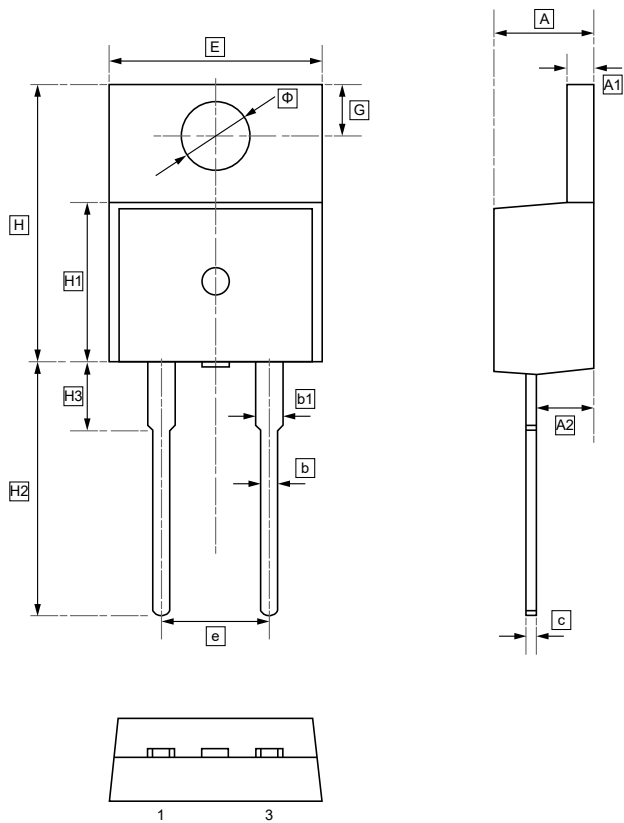


8. Typical Characterisitics





9.TO-220AC-2 Package Outline Dimensions



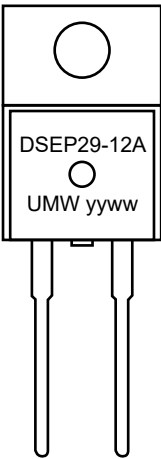
DIMENSIONS (mm are the original dimensions)

Symbol	A	A1	A2	b	b1	c	e	E	H	H1	H2	H3
Min	4.30	1.17	2.20	0.60	1.17	0.30	2.34	9.70	15.50	9.00	12.58	2.80
Max	4.70	1.37	2.60	1.00	1.37	0.70	2.74	10.10	15.90	9.40	13.58	3.20

Symbol	G	Φ
Min	2.60	3.40
Max	3.00	3.80



10.Ordering Information



yy: Year Code
ww: Week Code

Order Code	Package	Base QTY	Delivery Mode
UMW DSEP29-12A	TO-220AC-2	1000	Tube and box



11.Disclaimer

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